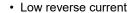


## Surface Mount SILICON EPITAXIAL SCHOTTKY BARRIER DIODE

#### 1. Features

· Low forward voltage

SOD-323





#### 2. Mechanical Data

- Case:Molded Plastic,SOD-323.
- Epoxy:UL 94V-0 rate flame retardant.
- Terminals:Plated Leads Solderable per MIL-STD-750, Method-2026.
- Marking:SU
- · Marking:marked on body.



## 3. Maximum Ratings

Electrical Characteristics Rating at 25 °C ambient temperature unless otherwise specified.

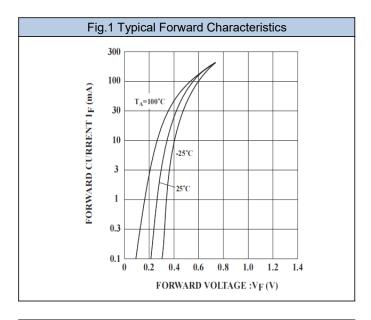
Characteristic	Symbol	Value	Unit
Maximum (Peak) Reverse Voltage	$V_{RM}$	45	V
Reverse Voltage	$V_R$	40	V
Maximum (Peak) Forward Current	I <sub>FM</sub>	300	mA
Average Forward Current	Io	100	mA
Surge Forward Current (10 ms)	I <sub>FSM</sub>	1	Α
Power Dissipation	P <sub>D</sub>	200	mW
Junction Temperature	T <sub>J</sub>	125	°C
Storage Temperature Range	T <sub>stg</sub>	-55 to+125	°C

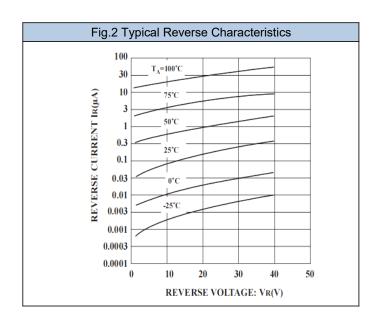
## 4. Electrical Characteristics (T<sub>A</sub>=25℃ unless otherwise noted)

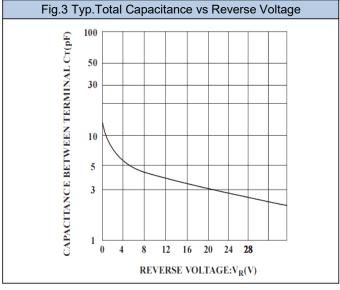
Parameters	Symbol	Cindition	Min	TYP	Max	Unit
Forward Voltage	V <sub>F</sub>	I <sub>F</sub> = 100mA	1	-	0.6	V
Reverse Current	I <sub>R</sub>	V <sub>R</sub> = 40V	-	-	5	μA
Total Capacitance	C <sub>T</sub>	$V_R = 0 V, f = 1 MHz$	-	-	25	pF



### 5. Rating And Characteristic Curves



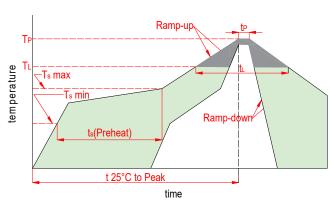






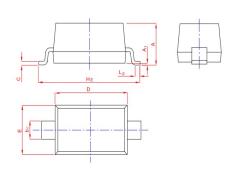
## **Surface Mount SILICON EPITAXIAL SCHOTTKY BARRIER DIODE**

## 6. Soldering Parameters

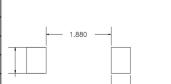


	Reflow Condition	Lead-free		
	Temp. min(T <sub>s</sub> (min))	150℃		
Pre Heat	Temp. max(T <sub>s</sub> (min))	200℃		
	Time(min to max)(t <sub>s</sub> )	60~120s		
Aver. ramp up rate(Liquidus Temp.)(T <sub>L</sub> )to peak		3℃/s max		
T <sub>S</sub> (max) to T <sub>L</sub> -Ramp-up Rate		3℃/s max		
Reflow	Temp.(T <sub>L</sub> )(Liquidus)	217℃		
	Temp.(t <sub>L</sub> )(Liquidus)	60~150s		
Peak Temp.(T <sub>P</sub> )		260 <sup>+0/-5</sup> ℃		
Time within actual peak Temp.(t <sub>p</sub> )		30s max		
Ramp-down Rate		6℃/s max		
Time $25^{\circ}$ to peak Tempe.( $T_p$ )		8 minutes max		
Do not exceed		260℃		

## 7. Dimensions

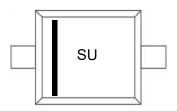


Dimensions	Inches		Millimeters		
Diffiensions	Min	Max	Min	Max	
A	0.031	0.047	0.800	1.200	
bp	0.010	0.016	0.250	0.400	
С	0.003	0.006	0.080	0.150	
D	0.063	0.071	1.600	1.800	
E	0.045	0.055	1.150	1.400	
H <sub>E</sub>	0.091	0.110	2.300	2.800	
A1	0.000	0.004	0.010	0.100	
L <sub>P</sub>	0.008	0.020	0.200	0.500	



Mounting PAD Layout

# 8. Part Marking System



## 9. Package Information

Package	Туре	Marking Code	Tape Width (mm)	Quantity(pcs)
SOD-323	1SS357	SU	8	3000



### Surface Mount SILICON EPITAXIAL SCHOTTKY BARRIER DIODE

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